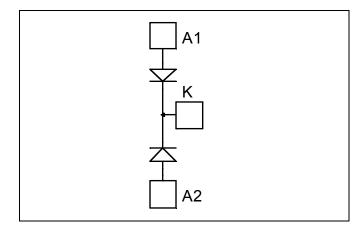


# Dual Common Cathode diodes Power Module

$$V_{RRM} = 1000V$$
  
 $I_C = 400A$  @  $T_C = 70^{\circ}C$ 



#### Application

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

#### **Features**

- Ultra fast recovery times
- Soft recovery characteristics
- Very low stray inductance
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance

#### Absolute maximum ratings

Α1

Symbol	Parameter			Max ratings	Unit	
$V_R$	Maximum DC reverse Voltage			1000	V	
$V_{RRM}$	Maximum Peak Repetitive Reverse	e Voltage	1000	V		
I <sub>F(A V)</sub>	Maximum Average Forward	Duty avala = 500/	$T_C = 25$ °C	500		
	Current	Duty cycle = 50%	$T_C = 70$ °C	400	Α	
I <sub>F(RMS)</sub>	RMS Forward Current	Duty cycle = 50%	$T_C = 45^{\circ}C$	500	7.1	
$I_{FSM}$	Non-Repetitive Forward Surge Cu	rrent 8.3 ms	$T_C = 45^{\circ}C$	3000		

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed.

Α2



#### All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

#### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 400 A$			2.1	2.7	
		$I_F = 600 A$			2.3		V
		$I_F = 400 A$	$T_j = 125$ °C		1.7		
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 1000V$ $T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$	$T_j = 25$ °C			250	μА
			$T_{j} = 125^{\circ}C$			1000	
$C_{T}$	Junction Capacitance	$V_R = 1000 V$			480		pF

**Dynamic Characteristics** 

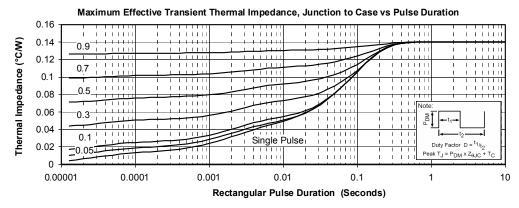
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
t <sub>rr</sub>	Reverse Recovery Time	$I_F=1 A, V_R=30 V$ $di/dt = 400 A/\mu s$	$T_j = 25$ °C		45		ns
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25^{\circ}C$		290		ns
чт	Reverse Recovery Time		$T_j = 125^{\circ}C$		340		113
Q <sub>rr</sub>	Reverse Recovery Charge	$I_F = 400 A$ $V_R = 667 V$	$T_j = 25^{\circ}C$		2.7		μC
ζm	reverse recovery charge	$di/dt = 800A/\mu s$	$T_j = 125^{\circ}C$		14.6		μΟ
$I_{RRM}$	Reverse Recovery Current	•	$T_j = 25^{\circ}C$		24		Α
1RRM	Reverse Recovery Current		$T_{j} = 125^{\circ}C$		72		
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 400  A$ $V_R = 667  V$ $di/dt = 4000  A/\mu s$			160		ns
Q <sub>rr</sub>	Reverse Recovery Charge		$T_j = 125$ °C		28.4		μС
$I_{RRM}$	Reverse Recovery Current				280		Α

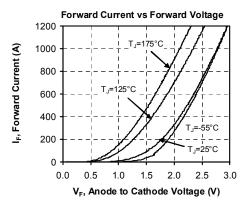
Thermal and package characteristics

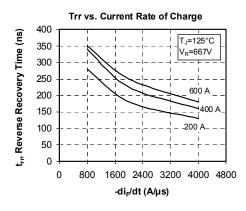
Symbol	Characteristic		Min	Typ	Max	Unit	
$R_{thJC}$	Junction to Case					0.14	°C/W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, I isol<1mA, 50/60Hz			2500			V
$T_{J}$	Operating junction temperature range			-40		175	°C
$T_{STG}$	Storage Temperature Range			-40		125	
$T_{C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	
Wt	Package Weight					280	g

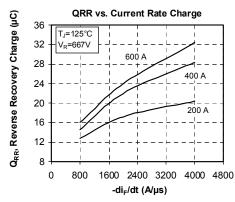


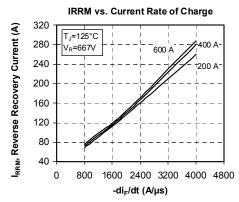
#### **Typical Performance Curve**

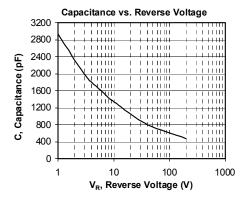


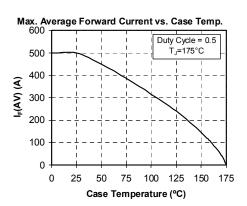






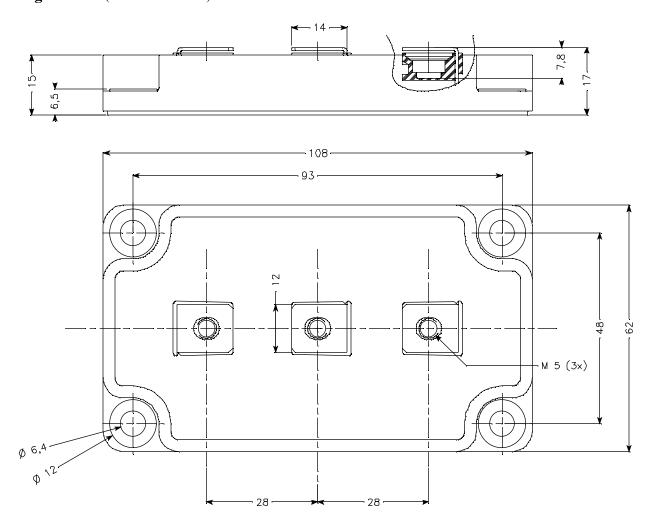








#### Package outline (dimensions in mm)



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